


Epoxy Nonwoven Aramid



55NT is an epoxy laminate and prepreg system, reinforced with a non-woven aramid substrate. This system combines compatibility with lead-free processing, using a high-temperature epoxy resin, with the low in-plane (X,Y) expansion and outstanding dimensional stability of non-woven aramid reinforcement.

Features:

- Low in-plane (X,Y) expansion of 6-9 ppm/°C allows attachment of SMT devices with minimal risk of solder joint failure due to CTE mismatch
- Nonwoven aramid organic reinforcement provides outstanding dimensional stability and enhanced registration for improved multilayer yields
- Tg of 170°C, decomposition temperature of 368°C, and Z-expansion of 3.5% between 50 -260°C ensures compatibility with most lead-free processes
- Polymeric reinforcement results in PCBs typically 25% lighter in weight than conventional glass-reinforced laminates
- Laser and plasma ablatable for high speed formation of microvias and other features as small as 25µm (µ0.001")
- Electrical and mechanical properties meeting the requirements of IPC-4101/55
- Compatible with lead-free processing

Typical Applications:

- Military and commercial avionics, missiles and missile defense, satellites, and other high-reliability SMT applications requiring low in-plane (x,y) CTE values
 - Other applications requiring low in-plane (x,y) CTE values, including chip carriers and multichip modules, where the chip carrier serves as an interposer for attachment to the underlying PCB
 - PCBs that are subjected to elevated temperatures during processing, such as lead-free soldering
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Typical Properties:

Property	Units	Value	Test Method
Electrical Properties			
Dielectric Constant @ 1 MHz	-	3.8	IPC TM-650 2.5.5.3
Dissipation Factor @ 1 MHz		0.015	IPC TM-650 2.5.5.3
Volume Resistivity			
C96/35/90	MΩ-cm	2.3×10^7	IPC TM-650 2.5.17.1
E24/125	MΩ-cm	6.6×10^7	IPC TM-650 2.5.17.1
Surface Resistivity			
C96/35/90	MΩ	1.8×10^8	IPC TM-650 2.5.17.1
E24/125	MΩ	1.6×10^8	IPC TM-650 2.5.17.1
Electrical Strength	Volts/mil (kV/mm)	1240 (48.8)	IPC TM-650 2.5.6.2
Arc Resistance	sec	165	IPC TM-650 2.5.1
Thermal Properties			
Glass Transition Temperature (Tg)			
DSC	°C	170	IPC TM-650 2.4.25D
Decomposition Temperature			
Initial	°C	351	IPC TM-650 2.4.24.6
5% weight loss	°C	368	IPC TM-650 2.4.24.6
T260	min	>60	IPC TM-650 2.4.24.1
T288	min	>60	IPC TM-650 2.4.24.1
T300	min	28	IPC TM-650 2.4.24.1
CTE (X,Y)	ppm/°C	6 - 9	IPC TM-650 2.4.41
CTE (Z)			
< Tg	ppm/°C	99	IPC TM-650 2.4.24C
> Tg	ppm/°C	259	IPC TM-650 2.4.24C
z-axis Expansion (50-260°C)	%	3.5	IPC TM-650 2.4.24C
Mechanical Properties			
Peel Strength to Copper (1 oz/35 micron)			
After Thermal Stress	lb./in (N/mm)	3.6 (0.6)	IPC TM-650 2.4.8C
At Elevated Temperatures	lb./in (N/mm)	3.6 (0.6)	IPC TM-650 2.4.8.2A
After Process Solutions	lb./in (N/mm)	3.6 (0.6)	IPC TM-650 2.4.8C
Young's Modulus CD/MD	Mpsi (GPa)	2.0 (13.8)	ASTM E111
Flexural Strength	kpsi (MPa)	38 (262)	ASTM D3039
Tensile Strength CD/MD	kpsi (MPa)	5 (35)	ASTM D3039
Poisson's Ratio	-		ASTM E13204
Physical Properties			
Water Absorption (0.062")	%	0.3	IPC TM-650 2.6.2.1A
Density	g/cm ³	1.38	ASTM D792 Method A
Thermal Conductivity	W/mK	0.2	ASTM E1461
Flammability	class	V-0	UL-94

Results listed above are typical properties, provided without warranty, expressed or implied, and without liability. Properties may vary, depending on design and application. Arlon reserves the right to change or update these values.

55NT

Availability:

Arlon Part Number	Glass Style	Resin (%)	Mil/Ply	Flow %
55NT147	E210	49	1.7	12
55NT247	E220	49	2.9	12
55NT347	E230	49	3.8	12
55NT153	E210	53	1.8	15
55NT253	E220	53	3.1	15
55NT353	E230	53	4.1	15

Recommended Process Conditions:

Process inner-layers through develop, etch, and strip using standard industry practices. Use brown oxide on inner layers. Adjust dwell time in the oxide bath to ensure uniform coating. Bake inner layers in a rack for 60 minutes at 107°C - 121°C (225°F - 250°F) immediately prior to lay-up. Vacuum desiccate the prepreg for 8 - 12 hours prior to lamination.

Lamination Cycle:

- 1) Pre-vacuum for 30 - 45 minutes
- 2) Control the heat rise to 4.5°C - 6.5°C (8°F - 12°F) per minute between 100°C and 150°C (210°F and 300°F). Vacuum lamination is preferred. Start point vacuum lamination pressures are shown in the table below:

Panel Size		Pressure	
in.	mm	psi	kg/cm ²
12 x 18	305 x 457	275	19
16 x 18	406 x 457	350	25
18 x 24	457 x 610	400	27

- 3) Product temperature at start of cure = 182°C (360°F)
- 4) Cure time at temperature = 90 minutes
- 5) Cool down under pressure at ≤ 6°C/min (10°F/min)

De-smear using alkaline permanganate or plasma with settings appropriate for polyimide; plasma is preferred for positive etchback

Conventional plating processes are compatible with 55NT

Standard profiling parameters may be used; chip breaker style router bits are not recommended Bake for 1 - 2 hours at 250°F (121°C) prior to solder to reflow of HASL

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For samples, technical assistance and customer service, please contact Arlon Electronic Materials at the following locations:

NORTH AMERICA:

Arlon EMD, 9433 Hyssop Drive, Rancho Cucamonga, CA
Tel: (909) 987-9533 • Fax: (909) 987-8541

FRANCE:

CCI Eurolam
9, rue Marcelin Bertholet
92160 Antony, France
Phone: (33) 146744747
Fax: (33) 146666313

GERMANY:

CCI Eurolam
Otto-Hahn-Str. 46 63303
Dreieich Germany
Phone: (49) 610339920
Fax: (49) 610339929

UK & SCANDINAVIA:

CCI Eurolam – UK
Ulness Walton Lane
Leyland, PR26 8NB, UK
Phone: (44) 1772452236
Fax: (44) 1772456859

ITALY:

CCI Eurolam
9, rue Marcelin Bertholet
92160 Antony, France
Phone: (33) 146744755
Fax: (33) 146666313

ISRAEL:

Tech Knowledge, Ltd. 159 Yigal
Alon Street,
Tel Aviv 6744367, Israel
Phone: (972) 36958117
Fax: (972) 36917117

H5-K 5B. Căcã cã
V^&@ [| * ^ Á & É C V D Á O P [É
493 Wen-zhong Jia Zhai ~ a Á
County HONG KONG
Ú@ } ^ K C I I D H G € i Á c k Á
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SINGAPORE:

C.T.S. Industries Pte Ltd
47 Kaki Bukit Place
Singapore 416225
Phone: (65) 6276 3328
Fax: (65) 6276 3336

JAPAN:

Nakao Corp.
12-8 Nihonbashi Hisamatsu-Cho Tokyo
103-0005 Japan
Phone: (81) 336623201
Fax: (81) 336617118

KOREA

UniMicrotek Co. Ltd.
478 Baekbeom-Ro, Bupyeong-Gu
Incheon, Korea
Phone: (82) 32-424-1776
Fax: (82) 505-720-1785

CHINA:

Zack Peng
Room 6A, Unit 2, Bldg 2
Jin Cheng Shi Dai, Tian Road
Shenzhen, China 518103
Phone: (86) 75528236491
Fax: (86) 75528236463

INDIA:

Synertec
301 Raheja Chambers, 12 Museum Rd
Bangalore, India 560001
Phone: (91) 80-25585432
Fax: (91) 80-25588565